



PNP SURFACE MOUNT SMALL SIGNAL TRANSISTOR IN SOT23

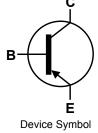
Features

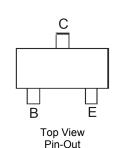
- Ideally Suited for Automatic Insertion
- Complementary NPN Types Available (BC846 BC848)
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT23
- Case material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)







Ordering Information (Notes 4 & 5)

Product	Compliance	ompliance Marking		Quantity per reel
BC856A-7-F	AEC-Q101	K3A	7	3,000
BC856B-7-F	AEC-Q101	K3B	7	3,000
BC856BQ-7-F	Automotive	K3B	7	3,000
BC856B-13-F	AEC-Q101	K3B	13	10,000
BC856BQ-13-F	Automotive	K3B	13	10,000
BC857A-7-F	AEC-Q101	K3A	7	3,000
BC857B-7-F	AEC-Q101	K3B	7	3,000
BC857BQ-7-F	Automotive	K3B	7	3,000
BC857B-13-F	AEC-Q101	K3B	13	10,000

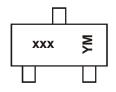
Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC857C-7-F	AEC-Q101	K3G	7	3,000
BC857C-13-F	AEC-Q101	K3G	13	10,000
BC858A-7-F	AEC-Q101	K3A	7	3,000
BC858B-7-F	AEC-Q101	K3B	7	3,000
BC858C-7-F	AEC-Q101	K3G	7	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

 5. Tape width is 8mm. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



xxx = Product Type Marking Code (Please see Ordering Information) YM = Date Code Marking

Y = Year ex: X = 2010 M = Month ex: 9 = September

Date Code Kev

Year	2010	20)11	2012	2	2013	2014		2015	2016		2017
Code	Χ		Y	Z		Α	В		С	D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteris	tic	Symbol	Value	Unit
	BC856	-80		
Collector-Base Voltage	BC857	V _{CBO}	-50	V
	BC858		-30]
	BC856		-65	
Collector-Emitter Voltage	BC857	$V_{\sf CEO}$	-45	V
	BC858		-30	
Emitter-Base Voltage		V _{EBO}	-5.0	V
Continuous Collector Current		I _C	-100	mA
Peak Collector Current		I _{CM}	-200	mA
Peak Emitter Current		I _{EM}	-200	mA

Characteristic	Symbol	Value	Unit	
Dower Dissipation	(Note 6)	Б	310	mW
Power Dissipation	(Note 7)	P _D	350	IIIVV
Thermal Decistores, Junction to Ambient	(Note 6)	D	403	00/11/
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ heta JA}$	357	°C/W
Thermal Resistance, Junction to Leads (Note 8)		$R_{ heta JL}$	350	°C/W
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-65 to +150	°C

ESD Ratings (Note 9)

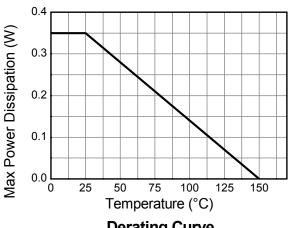
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

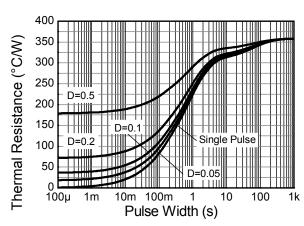
Notes:

- 6. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 7. For the device mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 8. Thermal resistance from junction to solder-point (at the end of the leads).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



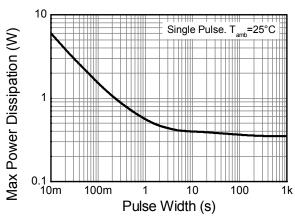
Thermal Characteristics and Derating Information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic				Min	Тур	Max	Unit	Test Condition
	В			-80				
Collector-Base Breakdown Voltage		BC857	BV_{CBO}	-50	_	_	V	$I_{C} = -10\mu A$
		BC858		-30				
Collector-Emitter Breakdown	Voltago	BC856		-65				
(Note 10)	vollage	BC857	BV_CEO	-45	_	_	V	$I_C = -10mA$
(14010-10)		BC858		-30				
Emitter-Base Breakdown Vol	tage		BV _{EBO}	-5	_	_	V	$I_E = -1\mu A$
Collector Cutoff Current			1			-15	μA	$V_{CB} = -30V$
Collector Cutoff Current			I _{CBO}			-4	μΑ	$V_{CB} = -30V, T_A = +150^{\circ}C$
		BC856				-15		V _{CE} = -80V
Collector Emitter Cutoff Curre	ent	BC857	I _{CES}	_	_	-15	nA	V _{CE} = -50V
		BC858				-15		V _{CE} = -30V
Small Signal Current Cain	BC856A / E	C857A / BC858A			200			
Small Signal Current Gain (Note 10)	BC856B / E	3C857B / BC858B	h _{fe}	_	330	_	_	
(14010-10)		7C / BC858C			600			
	BC856A / BC857A / BC858A BC856B / BC857B / BC858B				2.7	_	kΩ	I _C = -2.0mA, V _{CE} = -5V
Input Impedance (Note 10)			h _{ie}	_	4.5			
		BC857C / BC858C			8.7			
Output Admittance	BC856A / BC857A / BC858A BC856B / BC857B / BC858B		h _{oe}	_	18			f = 1.0kHz
(Note 10)					30	_	μS	
(11010-10)		7C / BC858C			60			_
Reverse Voltage Transfer		3C857A / BC858A			1.5x10 ⁻⁴			
Ratio (Note 10)	BC856B / BC857B / BC858B BC857C / BC858C		h _{re}	_	2x10 ⁻⁴	_	_	
rano (rioto ro)					3x10 ⁻⁴			
		3C857A / BC858A		125	180	250		
DC Current Gain (Note 10)	BC856B / BC857B / BC858B		h _{FE}	220	290	475	_	$I_C = -2.0 \text{mA}, V_{CE} = -5 \text{V}$
	BC857	7C / BC858C		420	520	800		
Collector-Emitter Saturation	Voltage (Note 1	0)	V _{CE(sat)}	_	-75	-300	mV	I _C = - 10mA, I _B = -0.5mA
		<u> </u>	0=(000)		-250	-650		$I_C = -100 \text{mA}, I_B = -5.0 \text{mA}$
Base-Emitter Turn-On Voltage (Note 10)			V _{BE(on)}	-600	-650	-750	mV	I _C = -2mA, V _{CE} = -5V
			BE(OII)	_	_	-820		$I_C = -10 \text{mA}, V_{CE} = -5 \text{V}$
Base-Emitter Saturation Voltage (Note 10)			V _{BE(sat)}	_	-700	_	mV	$I_C = -10$ mA, $I_B = -0.5$ mA
		` ,		-850			$I_C = -100 \text{mA}, I_B = -5 \text{mA}$	
Output Capacitance			C _{obo}		3	_	pF	V _{CB} = -10V, f = 1.0MHz
Transition Frequency			f _T	100	200	_	MHz	$V_{CE} = -5V, I_{C} = -10mA,$ f = 100MHz
Noise Figure			NF	_	2	10	dB	V_{CE} = -5V, I_{C} = -200 μ A R_{S} = 2k Ω , f = 1kHz Δf = 200Hz

Notes: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

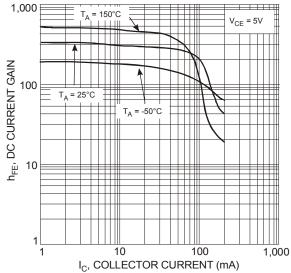
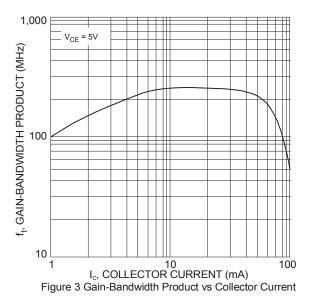


Figure 1 Typical DC Current Gain vs. Collector Current



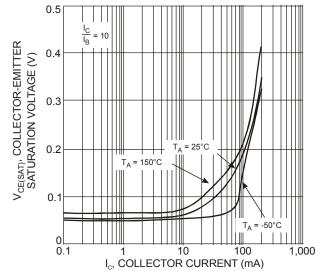
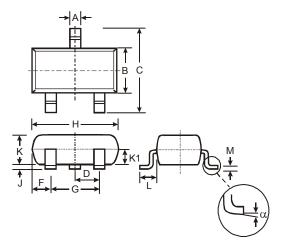


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current



Package Outline Dimensions

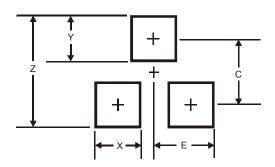
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
7	0.013	0.10	0.05				
K	0.903	1.10	1.00				
K1	-	-	0.400				
L	0.45	0.61	0.55				
М	0.085	0.18	0.11				
α	0°	8°	-				
All	Dimens	ions in	mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35



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